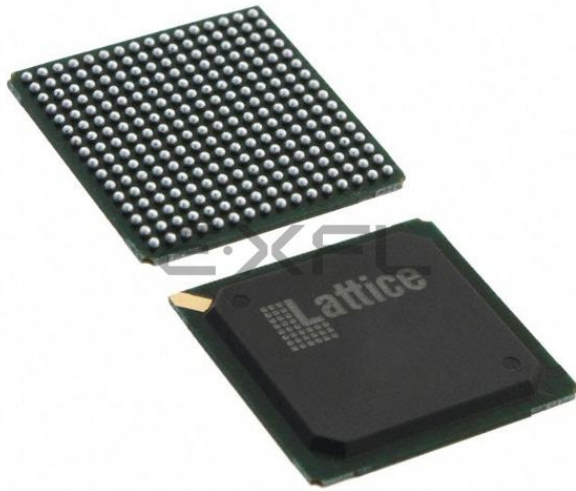




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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	2375
Number of Logic Elements/Cells	19000
Total RAM Bits	1246208
Number of I/O	140
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-BGA
Supplier Device Package	256-FPBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lfe2m20e-6f256c

sysMEM Memory

LatticeECP2/M devices contains a number of sysMEM Embedded Block RAM (EBR). The EBR consists of an 18-Kbit RAM with dedicated input and output registers.

sysMEM Memory Block

The sysMEM block can implement single port, dual port or pseudo dual port memories. Each block can be used in a variety of depths and widths as shown in Table 2-6. FIFOs can be implemented in sysMEM EBR blocks by implementing support logic with PFUs. The EBR block facilitates parity checking by supporting an optional parity bit for each data byte. EBR blocks provide byte-enable support for configurations with 18-bit and 36-bit data widths.

Table 2-6. sysMEM Block Configurations

Memory Mode	Configurations
Single Port	16,384 x 1 8,192 x 2 4,096 x 4 2,048 x 9 1,024 x 18 512 x 36
True Dual Port	16,384 x 1 8,192 x 2 4,096 x 4 2,048 x 9 1,024 x 18
Pseudo Dual Port	16,384 x 1 8,192 x 2 4,096 x 4 2,048 x 9 1,024 x 18 512 x 36

Bus Size Matching

All of the multi-port memory modes support different widths on each of the ports. The RAM bits are mapped LSB word 0 to MSB word 0, LSB word 1 to MSB word 1, and so on. Although the word size and number of words for each port varies, this mapping scheme applies to each port.

RAM Initialization and ROM Operation

If desired, the contents of the RAM can be pre-loaded during device configuration. By preloading the RAM block during the chip configuration cycle and disabling the write controls, the sysMEM block can also be utilized as a ROM.

Memory Cascading

Larger and deeper blocks of RAM can be created using EBR sysMEM Blocks. Typically, the Lattice design tools cascade memory transparently, based on specific design inputs.

Single, Dual and Pseudo-Dual Port Modes

In all the sysMEM RAM modes the input data and address for the ports are registered at the input of the memory array. The output data of the memory is optionally registered at the output.

EBR memory supports two forms of write behavior for single port or dual port operation:

1. Normal – Data on the output appears only during a read cycle. During a write cycle, the data (at the current address) does not appear on the output. This mode is supported for all data widths.

- MULT (Multiply)
- MAC (Multiply, Accumulate)
- MULTADDSUB (Multiply, Addition/Subtraction)
- MULTADDSUBSUM (Multiply, Addition/Subtraction, Accumulate)

The number of elements available on each block depends in the width selected from the three available options x9, x18, and x36. A number of these elements are concatenated for highly parallel implementations of DSP functions. Table 2-7 shows the capabilities of the block.

Table 2-7. Maximum Number of Elements in a Block

Width of Multiply	x9	x18	x36
MULT	8	4	1
MAC	2	2	—
MULTADDSUB	4	2	—
MULTADDSUBSUM	2	1	—

Some options are available in four elements. The input register in all the elements can be directly loaded or can be loaded as a shift register from previous operand registers. By selecting “dynamic operation” the following operations are possible:

- In the ‘Signed/Unsigned’ options the operands can be switched between signed and unsigned on every cycle.
- In the ‘Add/Sub’ option the Accumulator can be switched between addition and subtraction on every cycle.
- The loading of operands can switch between parallel and serial operations.

MULT sysDSP Element

This multiplier element implements a multiply with no addition or accumulator nodes. The two operands, A and B, are multiplied and the result is available at the output. The user can enable the input/output and pipeline registers. Figure 2-23 shows the MULT sysDSP element.

Figure 2-23. MULT sysDSP Element

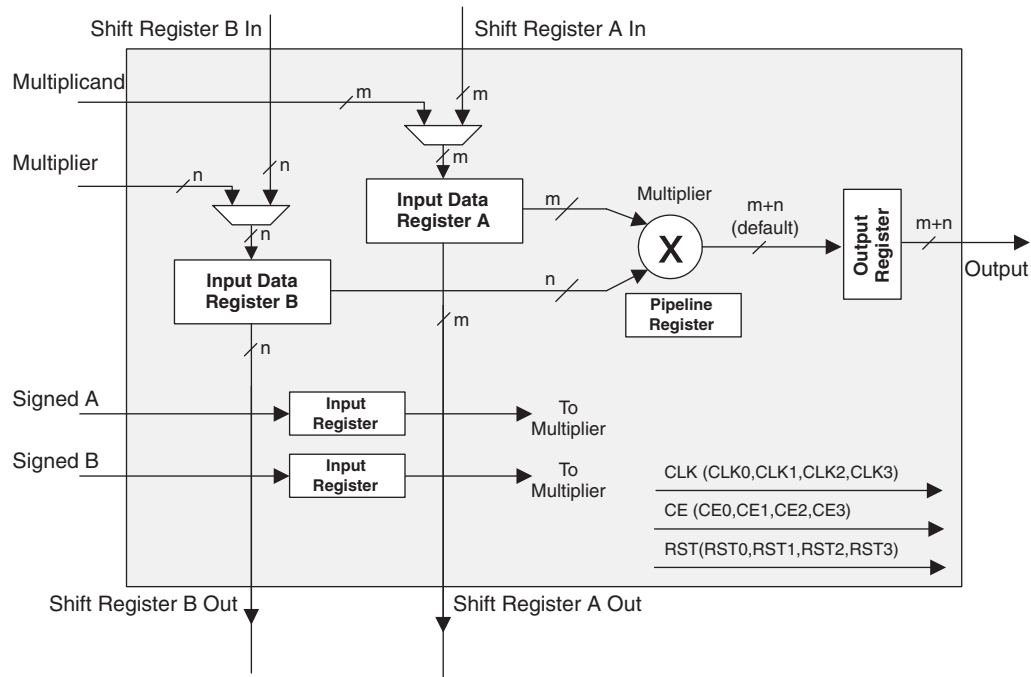
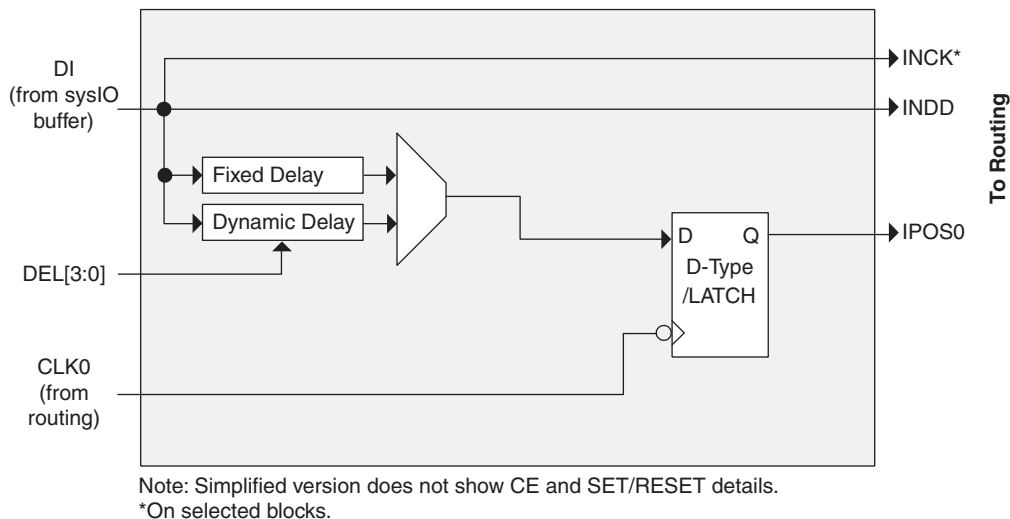


Figure 2-30. Input Register Block Top Edge



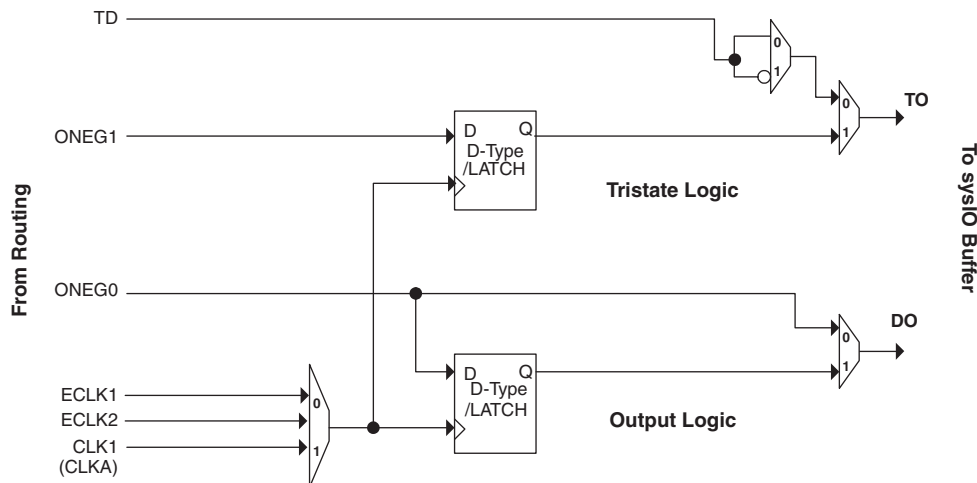
Output Register Block

The output register block provides the ability to register signals from the core of the device before they are passed to the sysI/O buffers. The blocks on the PIOs on the left, right and bottom contain a register for SDR operation that is combined with an additional latch for DDR operation. Figure 2-31 shows the diagram of the Output Register Block for PIOs on the left, right and the bottom edges. Figure 2-32 shows the diagram of the Output Register Block for PIOs on the top edge of the device.

In SDR mode, ONEG0 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured as a D-type or latch. In DDR mode, ONEG0 and OPOS0 are fed into registers on the positive edge of the clock. Then at the next clock cycle this registered OPOS0 is latched. A multiplexer running off the same clock selects the correct register for feeding to the output (D0).

By combining the output blocks of the complementary PIOs and sharing some registers from input blocks, a gearbox function can be implemented, that takes four data streams: ONEG0A, ONEG1A, ONEG1B and ONEG1B. Figure 2-32 shows the diagram using this gearbox function. For more information about this topic, please see information regarding additional documentation at the end of this data sheet.

Figure 2-32. Output and Tristate Block, Top Edge



Note: Simplified version does not show CE and SET/RESET details.

Tristate Register Block

The tristate register block provides the ability to register tri-state control signals from the core of the device before they are passed to the sys/O buffers. The block contains a register for SDR operation and an additional latch for DDR operation. Figure 2-31 shows the diagram of the Tristate Register Block with the Output Block for the left, right and bottom edges and Figure 2-32 shows the diagram of the Tristate Register Block with the Output Block for the top edge.

In SDR mode, ONEG1 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured a D-type or latch. In DDR mode, ONEG1 and OPOS1 are fed into registers on the positive edge of the clock. Then in the next clock the registered OPOS1 is latched. A multiplexer running off the same clock cycle selects the correct register for feeding to the output (DO).

Control Logic Block

The control logic block allows the selection and modification of control signals for use in the PIO block. A clock is selected from one of the clock signals provided from the general purpose routing, one of the edge clocks (ECLK1/ ECLK2) and a DQS signal provided from the programmable DQS pin and provided to the input register block. The clock can optionally be inverted.

DDR Memory Support

Certain PICs have additional circuitry to allow the implementation of high speed source synchronous and DDR memory interfaces. The support varies by the edge of the device as detailed below.

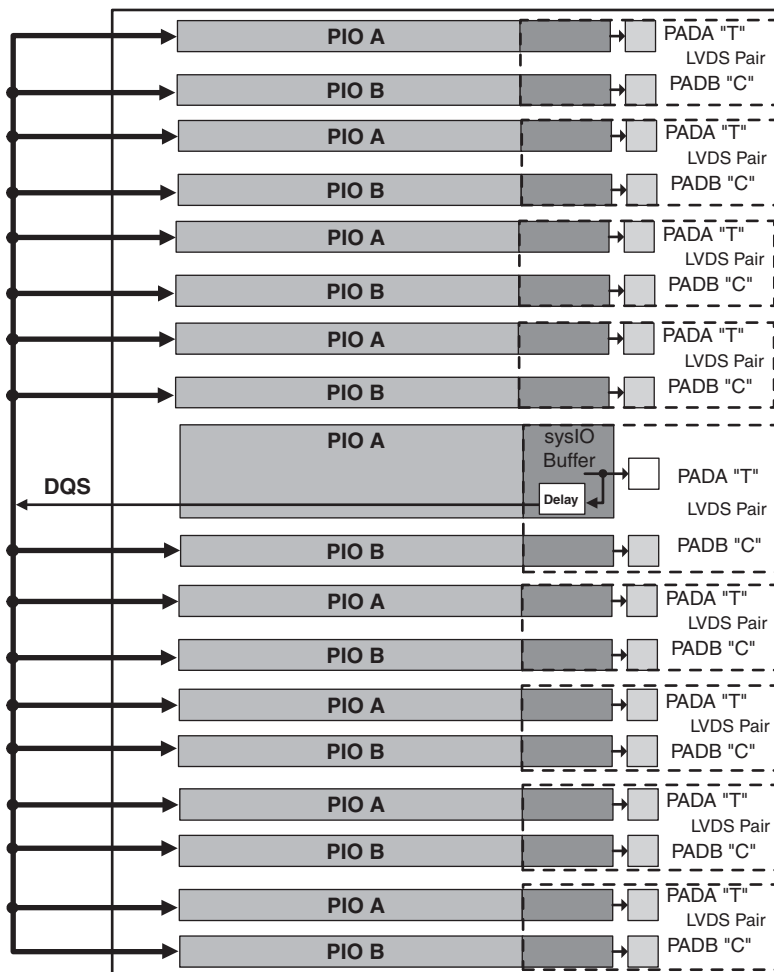
Left and Right Edges

PICs on these edges have registered elements that support DDR memory interfaces. One of every 16 PIOs contains a delay element to facilitate the generation of DQS signals. The DQS signal feeds the DQS bus that spans the set of 16 PIOs. Figure 2-33 shows the assignment of DQS pins in each set of 16 PIOs.

Bottom Edge

PICs on the bottom edge have registered elements that support DDR memory interfaces. One of every 18 PIOs contains a delay element to facilitate the generation of DQS signals. The DQS signal feeds the DQS bus that spans the set of 18 PIOs. Figure 2-34 shows the assignment of DQS pins in each set of 18 PIOs.

Figure 2-34. DQS Input Routing for the Bottom Edge of the Device



DLL Calibrated DQS Delay Block

Source synchronous interfaces generally require the input clock to be adjusted in order to correctly capture data at the input register. For most interfaces a PLL is used for this adjustment. However, in DDR memories the clock (referred to as DQS) is not free-running so this approach cannot be used. The DQS Delay block provides the required clock alignment for DDR memory interfaces.

The DQS signal (selected PIOs only, as shown in Figure 2-35) feeds from the PAD through a DQS delay element to a dedicated DQS routing resource. The DQS signal also feeds polarity control logic, which controls the polarity of the clock to the sync registers in the input register blocks. Figure 2-35 and Figure 2-36 show how the DQS transition signals are routed to the PIOs.

The temperature, voltage and process variations of the DQS delay block are compensated by a set of calibration (6-bit bus) signals from two dedicated DLLs (DDR_DLL) on opposite sides of the device. Each DLL compensates DQS delays in its half of the device as shown in Figure 2-35. The DLL loop is compensated for temperature, voltage and process variations by the system clock and feedback loop.

LatticeECP2/M External Switching Characteristics⁹

Over Recommended Operating Conditions

Parameter	Description	Device	-7		-6		-5		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
General I/O Pin Parameters (using Primary Clock without PLL) ¹									
t _{CO}	Clock to Output - PIO Output Register	LFE2-6	—	3.50	—	3.90	—	4.20	ns
		LFE2-12	—	3.50	—	3.90	—	4.20	ns
		LFE2-20	—	3.50	—	3.90	—	4.20	ns
		LFE2-35	—	3.50	—	3.90	—	4.20	ns
		LFE2-50	—	3.50	—	3.90	—	4.20	ns
		LFE2-70	—	3.70	—	4.10	—	4.40	ns
		LFE2M20	—	3.90	—	4.30	—	4.70	ns
		LFE2M35	—	3.90	—	4.30	—	4.70	ns
		LFE2M50	—	4.50	—	5.00	—	5.40	ns
		LFE2M70	—	4.50	—	5.00	—	5.40	ns
		LFE2M100	—	4.50	—	5.00	—	5.40	ns
t _{SU}	Clock to Data Setup - PIO Input Register	LFE2-6	0.00	—	0.00	—	0.00	—	ns
		LFE2-12	0.00	—	0.00	—	0.00	—	ns
		LFE2-20	0.00	—	0.00	—	0.00	—	ns
		LFE2-35	0.00	—	0.00	—	0.00	—	ns
		LFE2-50	0.00	—	0.00	—	0.00	—	ns
		LFE2-70	0.00	—	0.00	—	0.00	—	ns
		LFE2M20	0.00	—	0.00	—	0.00	—	ns
		LFE2M35	0.00	—	0.00	—	0.00	—	ns
		LFE2M50	0.00	—	0.00	—	0.00	—	ns
		LFE2M70	0.00	—	0.00	—	0.00	—	ns
		LFE2M100	0.00	—	0.00	—	0.00	—	ns
t _H	Clock to Data Hold - PIO Input Register	LFE2-6	1.40	—	1.70	—	1.90	—	ns
		LFE2-12	1.40	—	1.70	—	1.90	—	ns
		LFE2-20	1.40	—	1.70	—	1.90	—	ns
		LFE2-35	1.40	—	1.70	—	1.90	—	ns
		LFE2-50	1.40	—	1.70	—	1.90	—	ns
		LFE2-70	1.40	—	1.70	—	1.90	—	ns
		LFE2M20	1.40	—	1.70	—	1.90	—	ns
		LFE2M35	1.40	—	1.70	—	1.90	—	ns
		LFE2M50	1.80	—	2.10	—	2.30	—	ns
		LFE2M70	1.80	—	2.10	—	2.30	—	ns
		LFE2M100	1.80	—	2.10	—	2.30	—	ns

LatticeECP2/M External Switching Characteristics⁹ (Continued)

Over Recommended Operating Conditions

Parameter	Description	Device	-7		-6		-5		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
t _{DQVBS}	Data Valid Before DQS (DDR Write)	ECP2/M	0.250	—	0.250	—	0.250	—	UI
t _{DQVAS}	Data Valid After DQS (DDR Write)	ECP2/M	0.250	—	0.250	—	0.250	—	UI
f _{MAX_DDR2}	DDR Clock Frequency	ECP2/M	133	266	133	200	133	166	MHz
SPI4.2 I/O Pin Parameters Static Alignment^{4, 8, 11}									
	Maximum Data Rate	ECP2-20	—	750	—	622	—	622	Mbps
		ECP2-35	—	750	—	622	—	622	Mbps
		ECP2-50	—	750	—	622	—	622	Mbps
		ECP2-70	—	750	—	622	—	622	Mbps
		ECP2M20	—	622	—	622	—	622	Mbps
		ECP2M35	—	622	—	622	—	622	Mbps
		ECP2M50	—	622	—	622	—	622	Mbps
		ECP2M70	—	622	—	622	—	622	Mbps
		ECP2M100	—	622	—	622	—	622	Mbps
t _{DVACLKSPI}	Data Valid After CLK (Receive)	ECP2-20	—	0.25	—	0.25	—	0.25	UI
		ECP2-35	—	0.25	—	0.25	—	0.25	UI
		ECP2-50	—	0.25	—	0.25	—	0.25	UI
		ECP2-70	—	0.25	—	0.25	—	0.25	UI
		ECP2M20	—	0.21	—	0.21	—	0.21	UI
		ECP2M35	—	0.21	—	0.21	—	0.21	UI
		ECP2M50	—	0.21	—	0.21	—	0.21	UI
		ECP2M70	—	0.21	—	0.21	—	0.21	UI
		ECP2M100	—	0.21	—	0.21	—	0.21	UI
t _{DVECLKSPI}	Data Hold After CLK (Receive)	ECP2-20	0.75	—	0.75	—	0.75	—	UI
		ECP2-35	0.75	—	0.75	—	0.75	—	UI
		ECP2-50	0.75	—	0.75	—	0.75	—	UI
		ECP2-70	0.75	—	0.75	—	0.75	—	UI
		ECP2M20	0.79	—	0.79	—	0.79	—	UI
		ECP2M35	0.79	—	0.79	—	0.79	—	UI
		ECP2M50	0.79	—	0.79	—	0.79	—	UI
		ECP2M70	0.79	—	0.79	—	0.79	—	UI
		ECP2M100	0.79	—	0.79	—	0.79	—	UI
t _{DIASPI}	Data Invalid After Clock (Transmit)	ECP2-20	—	280	—	280	—	280	ps
		ECP2-35	—	280	—	280	—	280	ps
		ECP2-50	—	280	—	280	—	280	ps
		ECP2-70	—	280	—	280	—	280	ps
		ECP2M20	—	230	—	230	—	230	ps
		ECP2M35	—	230	—	230	—	230	ps
		ECP2M50	—	230	—	230	—	230	ps
		ECP2M70	—	230	—	230	—	230	ps
		ECP2M100	—	230	—	230	—	230	ps

Table 3-9. Channel Output Jitter - x20 Mode

Description	Frequency	Min.	Typ.	Max.	Units
Deterministic	3.125 Gbps	—	0.08	0.12	UI, p-p
Random	3.125 Gbps	—	0.27	0.51	UI, p-p
Total	3.125 Gbps	—	0.35	0.59	UI, p-p
Deterministic	2.5 Gbps	—	0.09	0.19	UI, p-p
Random	2.5 Gbps	—	0.23	0.34	UI, p-p
Total	2.5 Gbps	—	0.29	0.45	UI, p-p
Deterministic	1.25 Gbps	—	0.05	0.11	UI, p-p
Random	1.25 Gbps	—	0.16	0.22	UI, p-p
Total	1.25 Gbps	—	0.20	0.28	UI, p-p

Note: Values are measured with PRBS 2⁷-1, all channels operating, FPGA Logic active, I/Os around SERDES pins quiet, reference clock at x20 mode.

Table 3-10. SERDES/PCS Latency Breakdown (Parallel Clock Cycle)

Item	Description	Min.	Average	Max.	Fixed	Bypass	Units
Transmit Data Latency							
T1	FPGA Bridge Transmit ²	1	3	5		1	word clk
T2	8b10b Encoder	—	—	—	2	1	word clk
T3	SERDES Bridge Transmit	—	—	—	2	1	word clk
T4 ³	Serializer: 8-bit mode	—	—	—	15 + Δ1	—	UI + ps
	Serializer: 10-bit mode	—	—	—	18 + Δ1	—	UI + ps
Receive Data Latency							
R1 ³	Deserializer: 8-bit mode	—	—	—	10 + Δ2	—	UI + ps
	Deserializer: 10-bit mode	—	—	—	12 + Δ2	—	UI + ps
R2	SERDES Bridge Receive	—	—	—	2	1	word clk
R3	Word Alignment	3.1	—	4	—	0	word clk
R4	8b10b Decoder	—	—	—	1	1	word clk
R5	Clock Tolerance Compensation	7	15	23		1	word clk
R6	FPGA Bridge Receive ²	1	3	5		1	word clk

1. PCS internal parallel clock. This clock rate is the same as rxfullclk.

2. FPGA Bridge latency varies by the upsample/downsample FIFO read/write. The numbers given are for the 8b10b interface. The depth of the downsample/upsample FIFO is 4. The earliest read can be done after the write clock cycle (one clock) in downsample FIFO. The latest read will be done after the FIFO is full (4 + 1 = 5). For the 16b20b interface, the numbers are doubled: min. = 2, max. = 10. This latency depends on the internal FIFO flag operation.

3. Δ1 = -245ps, Δ2 = 700ps

Figure 3-12. Transmitter and Receiver Block Diagram

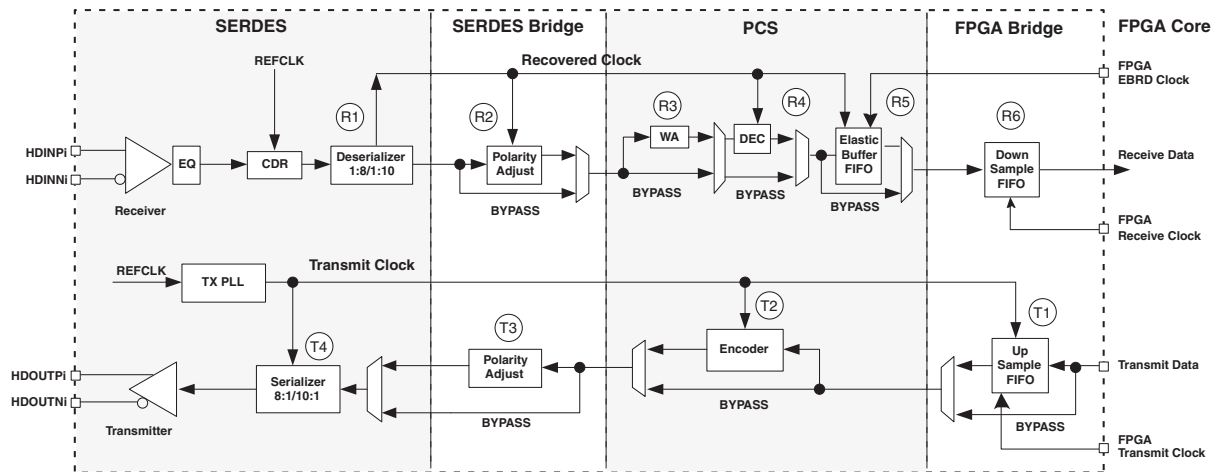
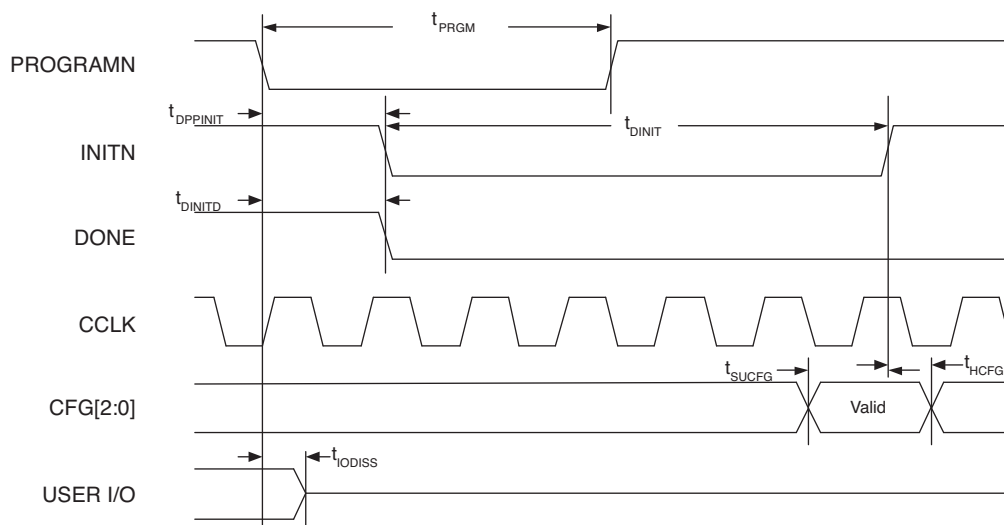


Figure 3-18. Configuration from PROGRAMN Timing



1. The CFG pins are normally static (hard wired)

Figure 3-19. Wake-Up Timing

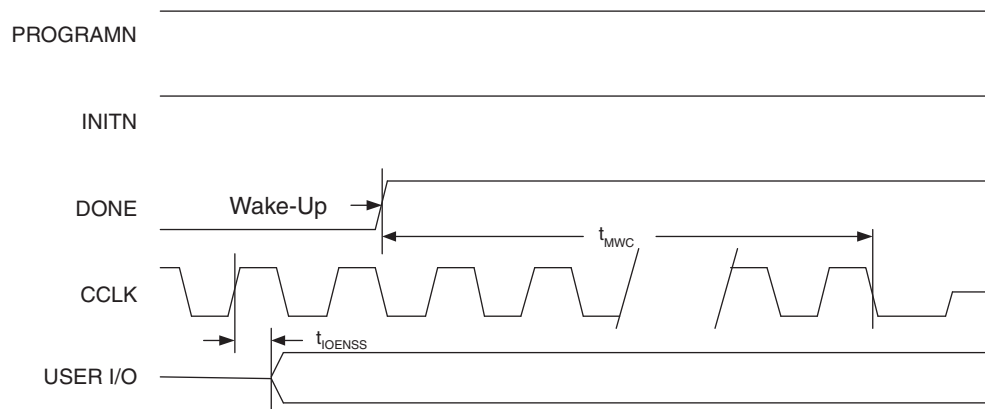
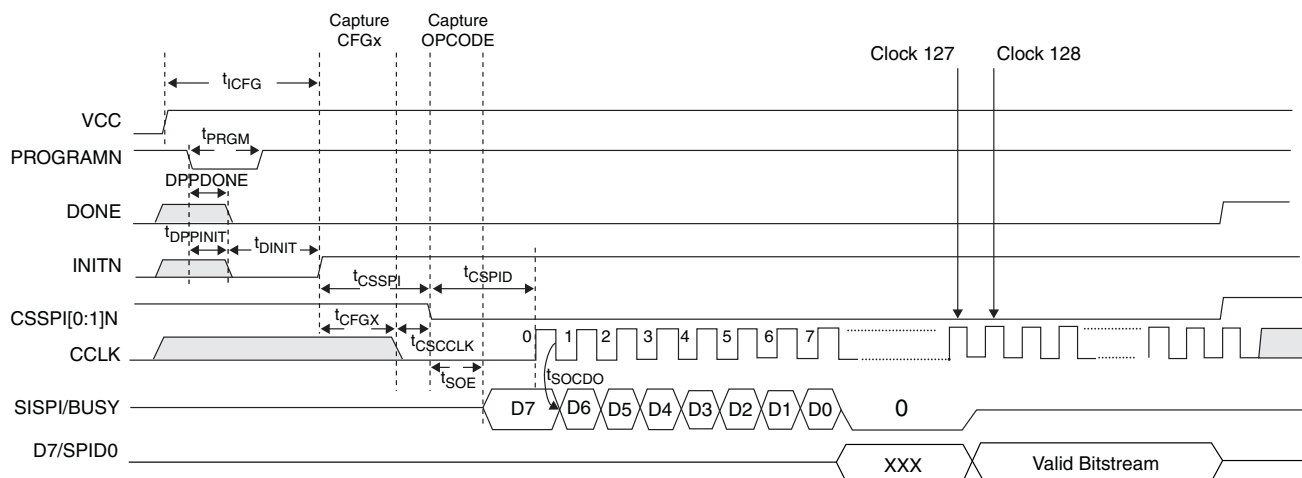


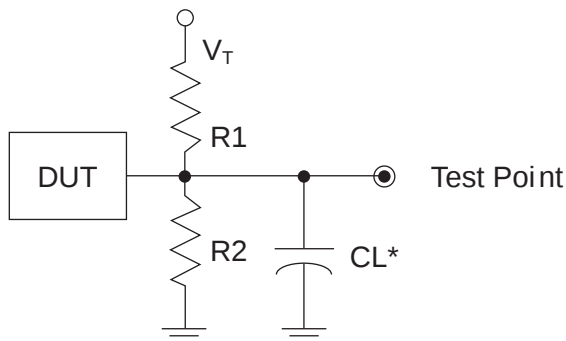
Figure 3-20. SPI/SPI_m Configuration Waveforms



Switching Test Conditions

Figure 3-22 shows the output test load that is used for AC testing. The specific values for resistance, capacitance, voltage, and other test conditions are shown in Table 3-19.

Figure 3-22. Output Test Load, LVTTTL and LVCMOS Standards



*CL Includes Test Fixture and Probe Capacitance

Table 3-19. Test Fixture Required Components, Non-Terminated Interfaces

Test Condition	R ₁	R ₂	C _L	Timing Ref.	V _T
LVTTTL and other LVCMOS settings (L -> H, H -> L)	∞	∞	0pF	LVCMOS 3.3 = 1.5V	—
				LVCMOS 2.5 = $V_{CCIO}/2$	—
				LVCMOS 1.8 = $V_{CCIO}/2$	—
				LVCMOS 1.5 = $V_{CCIO}/2$	—
				LVCMOS 1.2 = $V_{CCIO}/2$	—
LVCMOS 2.5 I/O (Z -> H)	∞	1M Ω		$V_{CCIO}/2$	—
LVCMOS 2.5 I/O (Z -> L)	1M Ω	∞		$V_{CCIO}/2$	V_{CCIO}
LVCMOS 2.5 I/O (H -> Z)	∞	100		$V_{OH} - 0.10$	—
LVCMOS 2.5 I/O (L -> Z)	100	∞		$V_{OL} + 0.10$	V_{CCIO}

Note: Output test conditions for all other interfaces are determined by the respective standards.

LFE2-6E/SE and LFE2-12E/SE Logic Signal Connections: 144 TQFP (Cont.)

LFE2-6E/SE					LFE2-12E/12SE			
Pin Number	Pin/Pad Function	Bank	Dual Function	Differential	Pin/Pad Function	Bank	Dual Function	Differential
46	NC	5			PB16B	5	BDQ15	C
47	GND	-			GND	-		
48	VCC				VCC	-		
49	PB8A	5	PCLKT5_0/BDQ6	T	PB26A	5	PCLKT5_0/BDQ24	T
50	PB8B	5	PCLKC5_0/BDQ6	C	PB26B	5	PCLKC5_0/BDQ24	C
51	GND	-			GND	-		
52	PB13A	4	PCLKT4_0/BDQ15	T	PB31A	4	PCLKT4_0/BDQ33	T
53	PB13B	4	PCLKC4_0/BDQ15	C	PB31B	4	PCLKC4_0/BDQ33	C
54	VCC	-			VCC	-		
55	PB14A	4	BDQ15	T	PB34A	4	BDQ33	T
56	PB14B	4	BDQ15	C	PB34B	4	BDQ33	C
57	PB16A	4	BDQ15	T	PB40A	4	BDQ42	T
58	PB16B	4	BDQ15	C	PB40B	4	BDQ42	C
59	PB18A	4	BDQ15	T	PB44A	4	BDQ42	T
60	PB18B	4	BDQ15	C	PB44B	4	BDQ42	C
61	GND	-			GND	-		
62	PB20A	4	BDQ24	T	PB48A	4	BDQ51	T
63	PB20B	4	BDQ24	C	PB48B	4	BDQ51	C
64	VCCIO4	4			VCCIO4	4		
65	PB22A	4	BDQ24	T	PB50A	4	BDQ51	T
66	PB22B	4	BDQ24	C	PB50B	4	BDQ51	C
67	PB24A	4	BDQS24	T	PB52A	4	BDQ51	T
68	PB24B	4	BDQ24	C	PB52B	4	BDQ51	C
69	PB26A	4	BDQ24	T	PB54A	4	BDQ51	T
70	PB26B	4	BDQ24	C	PB54B	4	BDQ51	C
71	PB28A	4	VREF2_4/BDQ24	T	PB55A	4	VREF2_4/BDQ51	T
72	PB28B	4	VREF1_4/BDQ24	C	PB55B	4	VREF1_4/BDQ51	C
73	CFG1	8			CFG1	8		
74	CFG2	8			CFG2	8		
75	PROGRAMN	8			PROGRAMN	8		
76	INITN	8			INITN	8		
77	CFG0	8			CFG0	8		
78	CCLK	8			CCLK	8		
79	DONE	8			DONE	8		
80	PR29A	8	D0/SPIFASTN		PR29A	8	D0/SPIFASTN	
81	GND	-			GND	-		
82	PR26A	8	D6		PR26A	8	D6	
83	VCC	-			VCC	-		
84	PR25B	8	D7/SPID0	C	PR25B	8	D7/SPID0	C
85	VCCIO8	8			VCCIO8	8		
86	PR25A	8	DI/CSSPI0N	T	PR25A	8	DI/CSSPI0N	T
87	PR24B	8	DOOUT/CSON	C	PR24B	8	DOOUT/CSON	C
88	PR24A	8	BUSY/SISPI	T	PR24A	8	BUSY/SISPI	T
89	VCCIO3	3			VCCIO3	3		
90	VCCAUX	-			VCCAUX	-		

LFE2-20E/SE Logic Signal Connections: 256 fpBGA

LFE2-20E/SE					
Ball Number	Ball Number	Ball/Pad Function	Bank	Dual Function	Differential
C3	C3	PL2A	7	VREF2_7	T (LVDS)*
C2	C2	PL2B	7	VREF1_7	C (LVDS)*
VCCIO	VCCIO	VCCIO7	7		
-	GND	GNDIO7	7		
D3	D3	PL7A	7	LDQ8	T
D4	D4	PL6A	7	LDQ8	T (LVDS)*
D2	D2	PL7B	7	LDQ8	C
GND	GND	GNDIO7	-		
E4	E4	PL6B	7	LDQ8	C (LVDS)*
B1	B1	PL13A	7	LDQ16	T
C1	C1	PL13B	7	LDQ16	C
F5	F5	PL15A	7	LDQ16	T
VCCIO	VCC	VCCIO	7		
F4	F4	PL14A	7	LDQ16	T (LVDS)*
G6	G6	PL15B	7	LDQ16	C
G4	G4	PL14B	7	LDQ16	C (LVDS)*
D1	D1	PL16A	7	LDQS16	T (LVDS)*
GND	GND	GNDIO7	-		
E1	E1	PL16B	7	LDQ16	C (LVDS)*
F3	F3	PL17A	7	LDQ16	T
G3	G3	PL17B	7	LDQ16	C
VCCIO	VCCIO	VCCIO7	7		
F2	F2	PL18A	7	LDQ16	T (LVDS)*
F1	F1	PL18B	7	LDQ16	C (LVDS)*
GND	GND	GNDIO7	-		
G2	G2	PL19A	7	PCLKT7_0/LDQ16	T
G1	G1	PL19B	7	PCLKC7_0/LDQ16	C
H6	H6	PL21A	6	PCLKT6_0/LDQ25	T (LVDS)*
VCCIO	VCCIO	VCCIO6	6		
H5	H5	PL21B	6	PCLKC6_0/LDQ25	C (LVDS)*
H4	H4	PL22A	6	VREF2_6/LDQ25	T
GND	GND	GNDIO6	-		
H3	H3	PL22B	6	VREF1_6/LDQ25	C
H2	H2	PL27A	6	LLM0_GDLLT_IN_A**/LDQ25	T (LVDS)*
H1	H1	PL27B	6	LLM0_GDLLC_IN_A**/LDQ25	C (LVDS)*
G10	G10	VCC	-		
J4	J4	PL28A	6	LLM0_GDLLT_FB_A/LDQ25	T
J5	J5	PL28B	6	LLM0_GDLLC_FB_A/LDQ25	C
J6	J6	LLM0_PLLCAP	6		
K4	K4	PL30A	6	LLM0_GPLLT_IN_A**/LDQ34	T (LVDS)*
GND	GND	GNDIO6	-		

LFE2-20E/SE Logic Signal Connections: 256 fpBGA (Cont.)

LFE2-20E/SE					
Ball Number	Ball Number	Ball/Pad Function	Bank	Dual Function	Differential
VCCIO	VCCIO	VCCIO1	1		
D12	D12	PT62A	1		T
B14	B14	PT61B	1		C
C14	C14	PT60B	1		C
A14	A14	PT61A	1		T
D13	D13	PT60A	1		T
C13	C13	PT59B	1		C
GND	GND	GNDIO1	-		
A13	A13	PT58B	1		C
B13	B13	PT59A	1		T
VCCIO	VCCIO	VCCIO1	1		
A12	A12	PT58A	1		T
B11	B11	PT57B	1		C
D11	D11	PT56B	1		C
A11	A11	PT57A	1		T
C11	C11	PT56A	1		T
-	GND	GNDIO1	1		
-	VCC	VCCIO	1		
D10	D10	PT46B	1		C
C10	C10	PT46A	1		T
GND	GND	GNDIO1	-		
B10	B10	PT45B	1		C
A9	A9	PT44B	1		C
A10	A10	PT45A	1		T
B9	B9	PT44A	1		T
VCCIO	VCCIO	VCCIO1	1		
A8	A8	PT43B	1		C
D9	D9	PT42B	1		C
B8	B8	PT43A	1		T
C9	C9	PT42A	1		T
GND	GND	GNDIO1	-		
B7	B7	PT41B	1		C
E9	E9	PT40B	1		C
A7	A7	PT41A	1		T
D8	D8	PT40A	1		T
VCCIO	VCCIO	VCCIO1	1		
A6	A6	PT39B	1	PCLKC1_0	C
B6	B6	PT39A	1	PCLKT1_0	T
E6	E6	XRES	1		
F8	F8	PT37B	0	PCLKC0_0	C
GND	GND	GNDIO0	-		
E8	E8	PT37A	0	PCLKT0_0	T

LFE2-70E/SE Logic Signal Connections: 900 fpBGA (Cont.)

LFE2-70E/SE				
Ball Number	Ball/Pad Function	Bank	Dual Function	Differential
W7	PL72B	6	LDQ71	C
W4	PL73A	6	LLM0_GDLLT_IN_A**/LDQ71	T (LVDS)*
W3	PL73B	6	LLM0_GDLLC_IN_A**/LDQ71	C (LVDS)*
W6	PL74A	6	LLM0_GDLLT_FB_A/LDQ71	T
GND	GNDIO6	-		
W8	PL74B	6	LLM0_GDLLC_FB_D/LDQ71	C
Y8	LLM0_PLLCAP	6		
Y1	PL76A	6	LLM0_GPLLT_IN_A**/LDQ80	T (LVDS)*
Y2	PL76B	6	LLM0_GPLLC_IN_A**/LDQ80	C (LVDS)*
Y5	PL77A	6	LLM0_GPLLT_FB_A/LDQ80	T
Y6	PL77B	6	LLM0_GPLLC_FB_A/LDQ80	C
Y4	PL78A	6	LDQ80	T (LVDS)*
VCCIO	VCCIO6	6		
Y3	PL78B	6	LDQ80	C (LVDS)*
AA6	PL79A	6	LDQ80	T
AA8	PL79B	6	LDQ80	C
AA2	PL80A	6	LDQS80	T (LVDS)*
GND	GNDIO6	-		
AA1	PL80B	6	LDQ80	C (LVDS)*
AA7	PL81A	6	LDQ80	T
AA5	PL81B	6	LDQ80	C
VCCIO	VCCIO6	6		
AA4	PL82A	6	LDQ80	T (LVDS)*
AA3	PL82B	6	LDQ80	C (LVDS)*
AB7	PL83A	6	LDQ80	T
AB5	PL83B	6	LDQ80	C
GND	GNDIO6	-		
AB2	PL84A	6	LDQ88	T (LVDS)*
AB1	PL84B	6	LDQ88	C (LVDS)*
AB8	PL85A	6	LDQ88	T
AB6	PL85B	6	LDQ88	C
VCCIO	VCCIO6	6		
AB4	PL86A	6	LDQ88	T (LVDS)*
AB3	PL86B	6	LDQ88	C (LVDS)*
AC7	PL87A	6	LDQ88	T
AC5	PL87B	6	LDQ88	C
GND	GNDIO6	-		
AC2	PL88A	6	LDQS88	T (LVDS)*
AC1	PL88B	6	LDQ88	C (LVDS)*
AC6	PL89A	6	LDQ88	T
VCCIO	VCCIO6	6		
AD6	PL89B	6	LDQ88	C
AD1	PL90A	6	LDQ88	T (LVDS)*

LFE2M20E/SE and LFE2M35E/SE Logic Signal Connections: 484 fpBGA

LFE2M20E/SE					LFE2M35E/SE				
Ball Number	Ball/Pad Function	Bank	Dual Function	Differential	Ball/Pad Function	Bank	Dual Function	Differential	
D1	PL2A	7	LDQ6	T (LVDS)*	PL2A	7	LDQ6	T (LVDS)*	
E1	PL2B	7	LDQ6	C (LVDS)*	PL2B	7	LDQ6	C (LVDS)*	
F1	PL3A	7	LDQ6	T	PL3A	7	LDQ6	T	
F2	PL3B	7	LDQ6	C	PL3B	7	LDQ6	C	
F5	PL4A	7	LDQ6	T (LVDS)*	PL4A	7	LDQ6	T (LVDS)*	
VCCIO	VCCIO7	7			VCCIO7	7			
G6	PL4B	7	LDQ6	C (LVDS)*	PL4B	7	LDQ6	C (LVDS)*	
F4	PL5A	7	LDQ6	T	PL5A	7	LDQ6	T	
F3	PL5B	7	LDQ6	C	PL5B	7	LDQ6	C	
G1	PL6A	7	LDQS6	T (LVDS)*	PL6A	7	LDQS6	T (LVDS)*	
GNDIO	GNDIO7	-			GNDIO7	-			
G2	PL6B	7	LDQ6	C (LVDS)*	PL6B	7	LDQ6	C (LVDS)*	
H1	PL7A	7	LDQ6	T	PL7A	7	LDQ6	T	
H2	PL7B	7	LDQ6	C	PL7B	7	LDQ6	C	
VCCIO	VCCIO7	7			VCCIO7	7			
H7	PL8A	7	LDQ6	T (LVDS)*	PL8A	7	LDQ6	T (LVDS)*	
H6	PL8B	7	LDQ6	C (LVDS)*	PL8B	7	LDQ6	C (LVDS)*	
G3	PL9A	7	VREF2_7/LDQ6	T	PL9A	7	VREF2_7/LDQ6	T	
H3	PL9B	7	VREF1_7/LDQ6	C	PL9B	7	VREF1_7/LDQ6	C	
GNDIO	GNDIO7	-			GNDIO7	-			
H5	PL11A	7	LUM0_SPLLT_IN_A	T (LVDS)*	PL11A	7	LUM0_SPLLT_IN_A/LDQ15	T (LVDS)*	
H4	PL11B	7	LUM0_SPLLC_IN_A	C (LVDS)*	PL11B	7	LUM0_SPLLC_IN_A/LDQ15	C (LVDS)*	
J1	PL12A	7	LUM0_SPLLT_FB_A	T	PL12A	7	LUM0_SPLLT_FB_A/LDQ15	T	
J2	PL12B	7	LUM0_SPLLC_FB_A	C	PL12B	7	LUM0_SPLLC_FB_A/LDQ15	C	
J3	PL13A	7		T (LVDS)*	PL13A	7	LDQ15	T (LVDS)*	
VCCIO	VCCIO7	7			VCCIO7	7			
J4	PL13B	7		C (LVDS)*	PL13B	7	LDQ15	C (LVDS)*	
J7	PL14A	7		T	PL14A	7	LDQ15	T	
J6	PL14B	7		C	PL14B	7	LDQ15	C	
GNDIO	GNDIO7	-			GNDIO7	-			
VCCIO	VCCIO7	7			VCCIO7	7			
K1	PL18A	7	LUM1_SPLLT_IN_A/LDQ22	T (LVDS)*	PL28A	7	LUM1_SPLLT_IN_A/LDQ32	T (LVDS)*	
K2	PL18B	7	LUM1_SPLLC_IN_A/LDQ22	C (LVDS)*	PL28B	7	LUM1_SPLLC_IN_A/LDQ32	C (LVDS)*	
J5	PL19A	7	LUM1_SPLLT_FB_A/LDQ22	T	PL29A	7	LUM1_SPLLT_FB_A/LDQ32	T	
K5	PL19B	7	LUM1_SPLLC_FB_A/LDQ22	C	PL29B	7	LUM1_SPLLC_FB_A/LDQ32	C	
VCCIO	VCCIO7	7			VCCIO7	7			
K7	PL20A	7	LDQ22	T (LVDS)*	PL30A	7	LDQ32	T (LVDS)*	
K6	PL20B	7	LDQ22	C (LVDS)*	PL30B	7	LDQ32	C (LVDS)*	
L6	PL21A	7	LDQ22	T	PL31A	7	LDQ32	T	
L7	PL21B	7	LDQ22	C	PL31B	7	LDQ32	C	
GNDIO	GNDIO7	-			GNDIO7	-			
L1	PL22A	7	LDQS22	T (LVDS)*	PL32A	7	LDQS32	T (LVDS)*	
L2	PL22B	7	LDQ22	C (LVDS)*	PL32B	7	LDQ32	C (LVDS)*	
M7	PL23A	7	LDQ22	T	PL33A	7	LDQ32	T	
VCCIO	VCCIO7	7			VCCIO7	7			
L5	PL23B	7	LDQ22	C	PL33B	7	LDQ32	C	
L3	PL24A	7	LDQ22	T (LVDS)*	PL34A	7	LDQ32	T (LVDS)*	

LFE2M100E/SE Logic Signal Connections: 900 fpBGA (Cont.)

LFE2M100E/SE				
Ball Number	Ball/Pad Function	Bank	Dual Function	Differential
M19	VCC	-		
M20	VCC	-		
N11	VCC	-		
N12	VCC	-		
N19	VCC	-		
N20	VCC	-		
P12	VCC	-		
P19	VCC	-		
R12	VCC	-		
R19	VCC	-		
T12	VCC	-		
T19	VCC	-		
U12	VCC	-		
U19	VCC	-		
V11	VCC	-		
V12	VCC	-		
V19	VCC	-		
V20	VCC	-		
W11	VCC	-		
W12	VCC	-		
W13	VCC	-		
W14	VCC	-		
W15	VCC	-		
W16	VCC	-		
W17	VCC	-		
W18	VCC	-		
W19	VCC	-		
W20	VCC	-		
Y12	VCC	-		
Y13	VCC	-		
Y18	VCC	-		
Y19	VCC	-		
D14	VCCIO0	0		
E6	VCCIO0	0		
E9	VCCIO0	0		
F12	VCCIO0	0		
K12	VCCIO0	0		
K13	VCCIO0	0		
D17	VCCIO1	1		
E22	VCCIO1	1		
E25	VCCIO1	1		
F19	VCCIO1	1		
K18	VCCIO1	1		

LFE2M70E/SE and LFE2M100E/SE Logic Signal Connections: 1152 fpBGA (Cont.)

LFE2M70E/SE				LFE2M100E/SE				
Ball Number	Ball/Pad Function	Bank	Dual Function	Differential	Ball/Pad Function	Bank	Dual Function	Differential
U22	GND	-			GND	-		
U23	GND	-			GND	-		
V12	GND	-			GND	-		
V13	GND	-			GND	-		
V15	GND	-			GND	-		
V16	GND	-			GND	-		
V17	GND	-			GND	-		
V18	GND	-			GND	-		
V19	GND	-			GND	-		
V20	GND	-			GND	-		
V22	GND	-			GND	-		
V23	GND	-			GND	-		
W12	GND	-			GND	-		
W13	GND	-			GND	-		
W15	GND	-			GND	-		
W16	GND	-			GND	-		
W17	GND	-			GND	-		
W18	GND	-			GND	-		
W19	GND	-			GND	-		
W20	GND	-			GND	-		
W22	GND	-			GND	-		
W23	GND	-			GND	-		
W26	GND	-			GND	-		
W31	GND	-			GND	-		
W4	GND	-			GND	-		
W9	GND	-			GND	-		
Y16	GND	-			GND	-		
Y17	GND	-			GND	-		
Y18	GND	-			GND	-		
Y19	GND	-			GND	-		
A11	NC	-			NC	-		
A12	NC	-			NC	-		
A23	NC	-			NC	-		
A24	NC	-			NC	-		
AA11	NC	-			NC	-		
AB11	NC	-			NC	-		
AC26	NC	-			NC	-		
AC30	NC	-			NC	-		
AD11	NC	-			NC	-		
AD12	NC	-			NC	-		
AD13	NC	-			NC	-		
AD14	NC	-			NC	-		
AD15	NC	-			NC	-		
AD19	NC	-			NC	-		
AD21	NC	-			NC	-		
AD22	NC	-			NC	-		
AD23	NC	-			NC	-		
AE10	NC	-			NC	-		
AE11	NC	-			NC	-		

LatticeECP2M Standard Series Devices, Conventional Packaging
Commercial

Part Number	I/Os	Voltage	Grade	Package	Pins	Temp.	LUTs (K)
LFE2M20E-5F484C	304	1.2V	-5	fpBGA	484	COM	20
LFE2M20E-6F484C	304	1.2V	-6	fpBGA	484	COM	20
LFE2M20E-7F484C	304	1.2V	-7	fpBGA	484	COM	20
LFE2M20E-5F256C	140	1.2V	-5	fpBGA	256	COM	20
LFE2M20E-6F256C	140	1.2V	-6	fpBGA	256	COM	20
LFE2M20E-7F256C	140	1.2V	-7	fpBGA	256	COM	20

Part Number	I/Os	Voltage	Grade	Package	Pins	Temp.	LUTs (K)
LFE2M35E-5F672C	410	1.2V	-5	fpBGA	672	COM	35
LFE2M35E-6F672C	410	1.2V	-6	fpBGA	672	COM	35
LFE2M35E-7F672C	410	1.2V	-7	fpBGA	672	COM	35
LFE2M35E-5F484C	303	1.2V	-5	fpBGA	484	COM	35
LFE2M35E-6F484C	303	1.2V	-6	fpBGA	484	COM	35
LFE2M35E-7F484C	303	1.2V	-7	fpBGA	484	COM	35
LFE2M35E-5F256C	140	1.2V	-5	fpBGA	256	COM	35
LFE2M35E-6F256C	140	1.2V	-6	fpBGA	256	COM	35
LFE2M35E-7F256C	140	1.2V	-7	fpBGA	256	COM	35

Part Number	I/Os	Voltage	Grade	Package	Pins	Temp.	LUTs (K)
LFE2M50E-5F900C	410	1.2V	-5	fpBGA	900	COM	50
LFE2M50E-6F900C	410	1.2V	-6	fpBGA	900	COM	50
LFE2M50E-7F900C	410	1.2V	-7	fpBGA	900	COM	50
LFE2M50E-5F672C	372	1.2V	-5	fpBGA	672	COM	50
LFE2M50E-6F672C	372	1.2V	-6	fpBGA	672	COM	50
LFE2M50E-7F672C	372	1.2V	-7	fpBGA	672	COM	50
LFE2M50E-5F484C	270	1.2V	-5	fpBGA	484	COM	50
LFE2M50E-6F484C	270	1.2V	-6	fpBGA	484	COM	50
LFE2M50E-7F484C	270	1.2V	-7	fpBGA	484	COM	50

Part Number	I/Os	Voltage	Grade	Package	Pins	Temp.	LUTs (K)
LFE2M70E-5F1152C	436	1.2V	-5	fpBGA	1152	COM	70
LFE2M70E-6F1152C	436	1.2V	-6	fpBGA	1152	COM	70
LFE2M70E-7F1152C	436	1.2V	-7	fpBGA	1152	COM	70
LFE2M70E-5F900C	416	1.2V	-5	fpBGA	900	COM	70
LFE2M70E-6F900C	416	1.2V	-6	fpBGA	900	COM	70
LFE2M70E-7F900C	416	1.2V	-7	fpBGA	900	COM	70